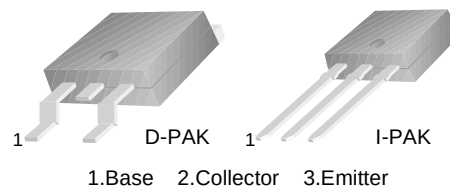


MJD32/32C

MJD32/32C

General Purpose Amplifier Low Speed Switching Applications D-PAK for Surface Mount Applications

- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular TIP32 and TIP32C



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	- 40	V
	: MJD32 : MJD32C	- 100	V
V_{CEO}	Collector-Emitter Voltage	- 40	V
	: MJD32 : MJD32C	- 100	V
V_{EBO}	Emitter-Base Voltage	- 5	V
I_C	Collector Current (DC)	- 3	A
I_{CP}	Collector Current (Pulse)	- 5	A
I_B	Base Current	- 1	A
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	15	W
	Collector Dissipation ($T_a=25^\circ\text{C}$)	1.56	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
$V_{CEO(sus)}$	* Collector-Emitter Sustaining Voltage	$I_C = - 30\text{mA}$, $I_B = 0$	-40		V
	: MJD32 : MJD32C				V
I_{CEO}	Collector Cut-off Current	$V_{CE} = - 40\text{V}$, $I_B = 0$ $V_{CE} = - 60\text{V}$, $I_B = 0$		-50	μA
	: MJD32 : MJD32C				μA
I_{CES}	Collector Cut-off Current	$V_{CE} = - 40\text{V}$, $V_{BE} = 0$ $V_{CE} = - 100\text{V}$, $V_{BE} = 0$		-20	μA
	: MJD32 : MJD32C				μA
I_{EBO}	Emitter Cut-off Current	$V_{BE} = - 5\text{V}$, $I_C = 0$		-1	mA
h_{FE}	* DC Current Gain	$V_{CE} = - 4\text{V}$, $I_C = - 1\text{A}$ $V_{CE} = - 4\text{V}$, $I_C = - 3\text{A}$	25 10	50	
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = - 3$, $I_B = - 375\text{mA}$		-1.2	V
$V_{BE(on)}$	* Base-Emitter ON Voltage	$V_{CE} = - 4\text{A}$, $I_C = - 3\text{A}$		-1.8	V
f_T	Current Gain Bandwidth Product	$V_{CE} = -10\text{V}$, $I_C = - 500\text{mA}$	3		MHz

* Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

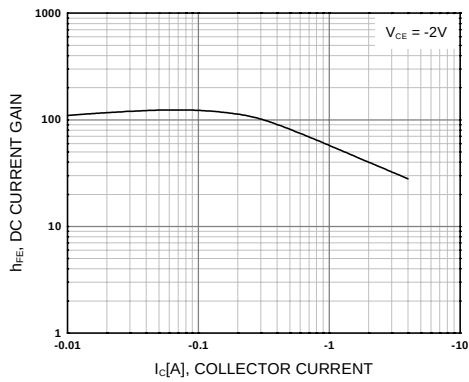


Figure 1. DC current Gain

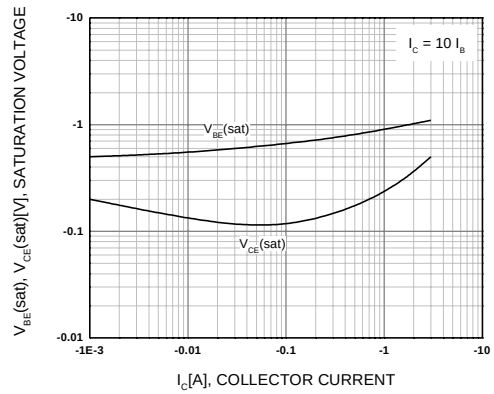


Figure 2. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

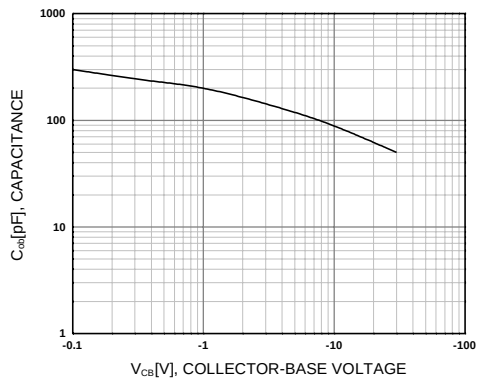


Figure 3. Collector Capacitance

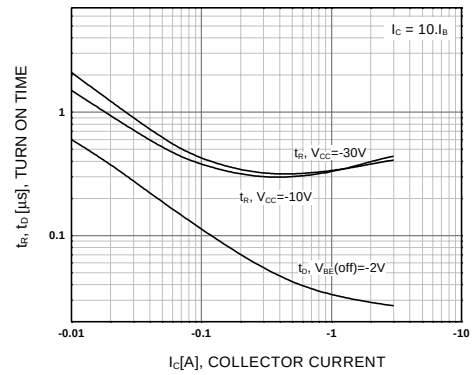


Figure 4. Turn On Time

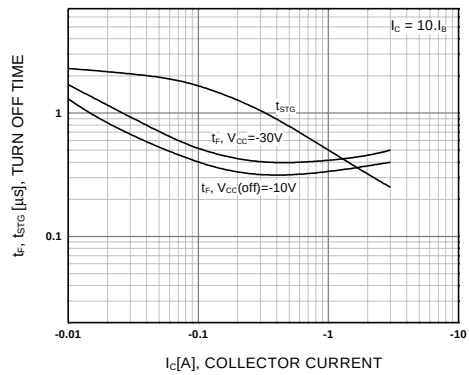


Figure 5. Turn Off Time

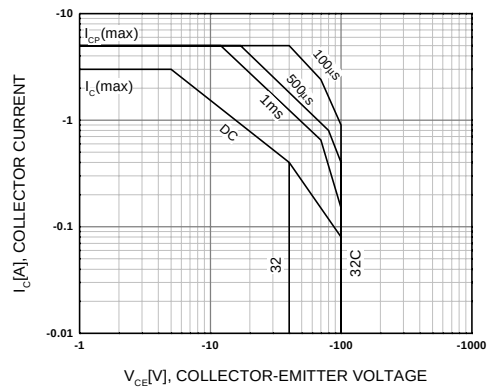


Figure 6. Safe Operating Area

Typical Characteristics (Continued)

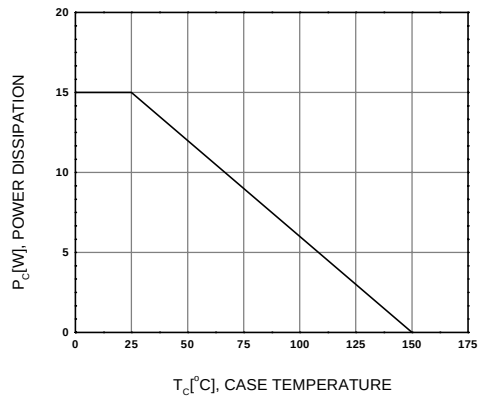
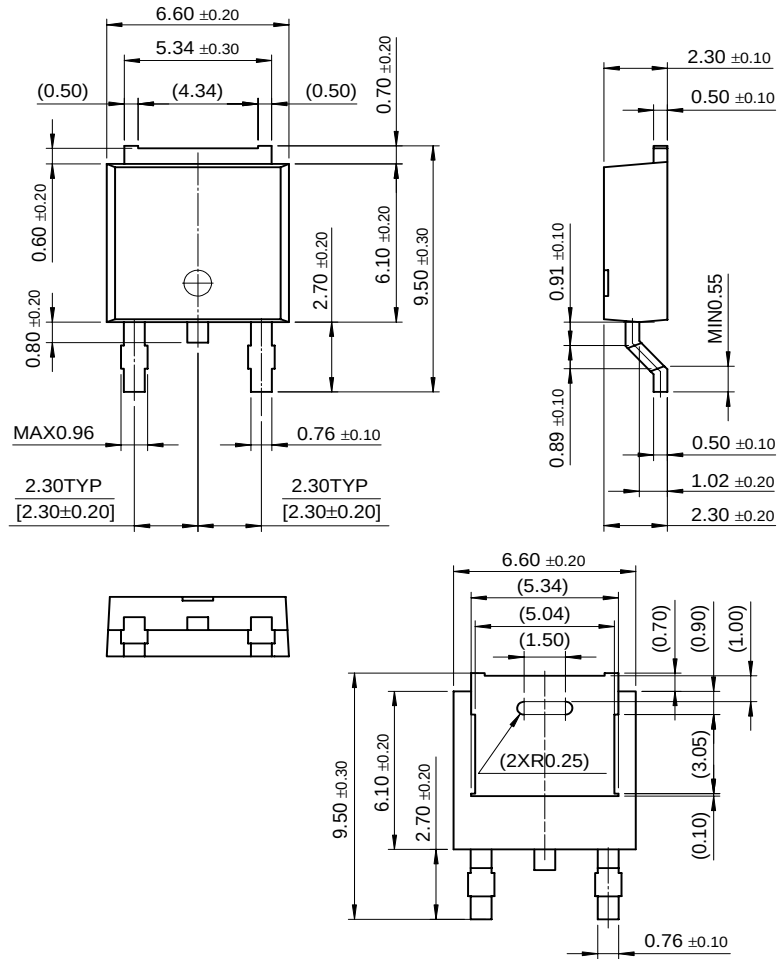


Figure 7. Power Derating

Package Dimensions

D-PAK



Dimensions in Millimeters

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